

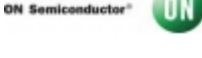


	<h2 style="color: red;">FQP13N50</h2>
	<p><b>Hersteller-Teilenummer:</b> FQP13N50</p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 500V 12.5A TO-220</p> <p><b>Datenblätter:</b> <a href="#">1.FQP13N50.pdf</a> <a href="#">2.FQP13N50.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 34951 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQP13N50
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 500V 12.5A TO-220
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	34951 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	170W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	12.5A (Tc)
Rds On (Max) @ Id, Vgs	430 mOhm @ 6.25A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2300pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube

FQP13N50 ist neu im Original, Suche FQP13N50 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N50 Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQP13N50: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQP13N50C</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 13A TO-220</p>	 <p><b>FQP13N60C</b> VB FQP13N60C VB</p>	 <p><b>FQP13N50C_F105</b> AMI Semiconductor / ON Semiconductor IC POWER MANAGEMENT</p>	 <p><b>FQP13N10L</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>
 <p><b>FQP13N50C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 13A TO-220</p>	 <p><b>FQP13N10C</b> FSC FQP13N10C FSC</p>	 <p><b>FQP13N10</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>	 <p><b>FQP140N03</b> Fairchild/ON Semiconductor FQP140N03 FAIRCHILD</p>

### heiße Teile

Mehr

⊗ FQP11N50CF	↔ FQP11N60	⇒ FQP11N60C	D FQP11N65C	⇒ FQP11P06
⊣ FQP11P06	⊗ FQP12N20	D FQP12N60	⇒ FQP12N60	⇒ FQP12N60C
⊗ FQP12N60C	⊣ FQP12N65C	⊗ FQP12P10	↔ FQP12P10	⇒ FQP12P20
D FQP12P20	⊗ FQP13N06	⊣ FQP13N06	⊗ FQP13N06L	⇒ FQP13N06L
⇒ FQP13N10	↔ FQP13N10	⊗ FQP13N10L	⊣ FQP13N10L	⇒ FQP13N50
↔ FQP13N50C	⇒ FQP13N50C	D FQP13N60C	⊗ FQP140N03	⊣ FQP140N03L
⊗ FQP14N15	D FQP14N15	⇒ FQP14N30	↔ FQP14N30	⇒ FQP14N80
⊣ FQP14N80C	⊗ FQP15N16	↔ FQP15N30	⇒ FQP15N50	⇒ FQP15N60
⊗ FQP15N65	⊣ FQP15N80	⊗ FQP15P12	D FQP15P12	⇒ FQP16N15
↔ FQP16N15	⊗ FQP16N25	⊣ FQP16N25	⊗ FQP16N25C	⇒ FQP16N25C

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